

राष्ट्रीय प्रौद्योगि की संस्थान सिलचर National Institute of Technology Silchar

(राष्ट्रीय महत्व का संस्थान)

(An Institute of National Importance)

www.nits.ac.in, Phone: 03842-242914, Fax: 03842-224797, Assam-788010 (INDIA)

Date: 06-02-2023

Advertisement No.: NITS/Dean-RC/Physics/623/01/2023

Applications are invited from Indian citizens for a temporary of post of Project Associate 1 for the DST-SERB sponsored project in the Department of Physics NIT Silchar.

Title of the project	Development of visible active multiphasic titania-metal oxide nanohetero junction photo catalyst with enhanced green hydrogen production capacity and test its utility in an indigenously fabricated prototype solar photocatalytic reactor for large scale applications.				
Sponsored Agency	DST-SERB				
Project sanction number	CRG/2022/000392				
No. of posts	01				
Duration	1 year and Extendable Till the completion of the project (23/01/2026)				
Principal Investigator (P.I)	Dr. Ranjith G. Nair				

General Information and Terms & Conditions

1.	Age Limit	35 years
2.	Essential Qualification	MSc. in Physics
3.	Desirable Experience	Experience in Material Synthesis & Characterization
4.	Salary	Rs. 31,000/- p.m. for candidates with NET/GATE qualification. Rs. 25,000/- p.m. for candidates without NET/GATE qualification. HRA @9% if Institute Accommodation is not provided.
5.	Relaxation on qualification and age	Relaxation as per Govt of India Rules.
6.	Last date for receiving the filled up application form by email	03-03-2023
7.	Reporting	Applicants are also requested to send the soft copy of the duly filled application along with C.V. &all necessary documents to the P.I through email: rgnair@phy.nits.ac.in
8.	Date of interview, time, and venue	Interview date and mode (online/offline) will be notified in due course of time through email.
9.	No objection certificate	Employed candidates are to submit no objection certificate from his/her employer at the time of interview.
10.	Institute right	The Institute has the discretion to restrict the number of candidates to be called for the interview on the basis of screening. No candidate may be recruited if suitable candidates are not found.
11.	Signing of the agreement	Selected candidates shall have to sign an agreement at the time of joining.

Sd/-

Associate Dean (R&C)

NIT Silchar.

National Institute of Technology Silchar

FORMAT of APPLICATION

for **Project Associate 1**

Paste recent
passport siz
colored
photograph

1.	Advertisement no	dated:					
2.	Title of the Project						
			•••••				
3.	Department:						
4.	Name of the applicant	(in block letters):					
5.	Father's/Husband's N	ame:					
6.	Date of Birth (DD-MM-YYYY):						
7.	Age as on 03-03-2023:						
8.	Postal Address:						
	E-mail:	Phone no.:					
9.	Permanent Address:						
10.	Nationality:						
11.	Marital Status:						
12.	Whether belongs to SC	/ST/PH/OBC/EWS: (If yes, attach certificat	e):				
13.	Educational Qualificati	on: (Starting from Class X) (Proof needs to be	e attached)				

Exam. passed	Board/ University	Divi sion	% age of marks / CPI	Year of passing	Subjects

I. NET					II. GATE			
Subj	ject	Qualifying date	Valid upto	Valid upto		Score	Valid upto	
15. De S1. No.	N	of employm ame of the rganization	nents (Proof nee	eds to be a	ttached): Scale of pay and present pay	Nat	ure of duty	
					*			
16. Aı	ny ot	her relevant	information th		y like to furnis	sh:		
			Declaration	ı				
		re that the ab	oove informatio	on are true	and correct to	the best o	of my	

Signature of the applicant

Date:

Place

14. NET/GATE Examinations Passed (Proof needs to be attached):